

Figure.S1. SS-PFM curves. (a) The butterfly-shaped amplitude loops; (b) the phase loops

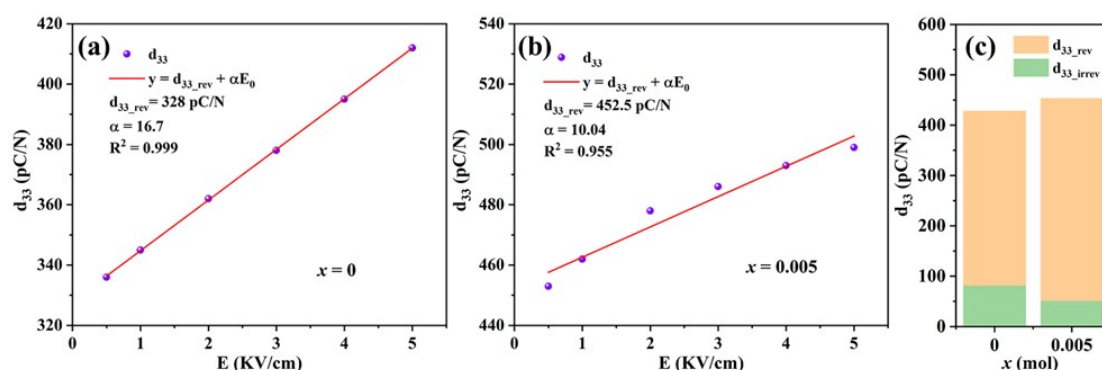


Figure S2. Rayleigh fitting curve of (a) $x = 0$; (b) $x = 0.0075$; (c) Piezoelectric contribution calculation for d_{33_rev} and d_{33_irrev} .

Phase field simulation

We employed Phase-field simulations to simulate the microstructure evolution under stress temperature field of samples with compositions $x = 0$ and $x = 0.005$. The size of the simulation model is 1000×600 nm², and the total free energy includes the following terms:

$$F = \int_V (f_{bulk} + f_{grad} + f_{elas} + f_{elec}) dV + \int_V f_{localelec} dV \quad (1)$$

$$\begin{aligned} f_{bulk} &= \alpha_1 (p_1^2 + p_2^2 + p_3^2) + \alpha_{11} (p_1^2 + p_2^2 + p_3^2)^2 + \alpha_{111} (p_1^2 + p_2^2 + p_3^2)^3 + (p_1^2 p_2^2 \\ &+ \alpha_{112} (p_1^4 p_2^2 + p_2^4 p_3^2 + p_1^4 p_3^2 + p_1^2 p_2^4 + p_1^2 p_3^4 + p_2^2 p_3^4 + p_1^2 p_3^4) + \alpha_{113} (p_1^2 \\ &p_2^2 p_3^2) \end{aligned} \quad (2)$$

Where the term f_{bulk} in Eq. (1) describes the bulk free energy density, expressed by Landau's free energy term in Eq. (2). α_1 , α_{11} , α_{12} are Landau coefficients depending on

defect concentration c and temperature T . α_{111} , α_{112} , α_{113} are constant coefficients. It should be noticed that the multiple terms in Eq. (2) decide the stability of ferroelectric phases (R, T, O, or C) and barriers between different ferroelectric phases. The global field effect f_{grad} can be described by the associated coefficients referred ^[1-3]. The f_{elas} reflects the long-range elastic interaction energy. The last term $f_{\text{localelec}}$ in Eq. (1) represents the local field effect caused by doped defects.

The temporal evolution of the domain structure can be obtained by solving the time-dependent Ginzburg-Landau (TDGL) function as Eq. (3)

$$\frac{dP_i(x,t)}{dt} = -M \frac{\delta F}{\delta P_i(x,t)}, i = 1, 2, 3 \quad (3)$$

where M is the kinetic coefficient related to the domain mobility and t is time. Further mathematical transformation was employed to obtain the symmetry contours from the calculated vector maps. The corresponding simulation results are presented in Fig. 5 (h).

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